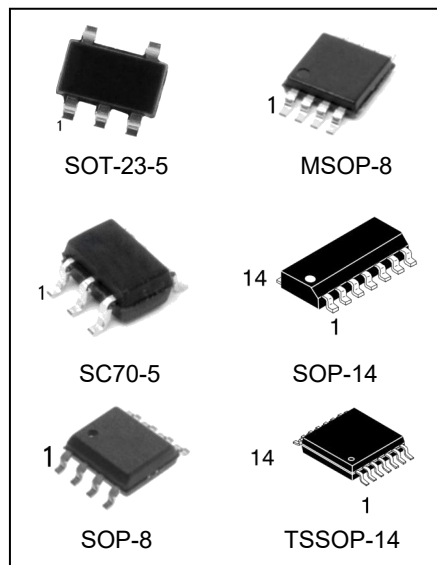


1MHz, 45μA, CMOS, Rail-to-Rail OPERATIONAL AMPLIFIERS

FEATURES

- LOW IQ: 45μA typical
- LOW COST
- RAIL-TO-RAIL INPUT AND OUTPUT
- SINGLE SUPPLY: +2.1V to +5.5V
- INPUT BIAS CURRENT: 0.5pA
- HIGH SPEED: POWER WITH BANDWIDTH: 1MHz
- SMALL PACKAGE:
HXA348A Available in SOT23-5 、SC70-5 and SOP-8 Packages
HXA2348A Available in MSOP-8 and SOP-8 Packages
HXA4348A Available in SOP-14 and TSSOP-14 Packages



ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
HXA348AIDBVRG	SOT-23-5	A348	REEL	3000pcs/reel
HXA348AIDCKRG	SC70-5	A348	REEL	3000pcs/reel
HXA348AIDRG	SOP-8	A348AI	REEL	2500pcs/reel
HXA348AIDRG4	SOP-8	A348AI	REEL	4000pcs/reel
HXA2348AIDRG	SOP-8	A2348AI	REEL	2500pcs/reel
HXA2348AIDRG4	SOP-8	A2348AI	REEL	40.00pcs/reel
HXA2348AIDGKRG	MSOP-8	2348AI	REEL	3000pcs/reel
HXA4348AIDRG	SOP-14	HXA4348AI	REEL	2500pcs/reel
HXA4348AIDRG4	SOP-14	HXA4348AI	REEL	4000pcs/reel
HXA4348AIPWRG	TSSOP-14	A4348AI	REEL	2500pcs/reel

DESCRIPTION

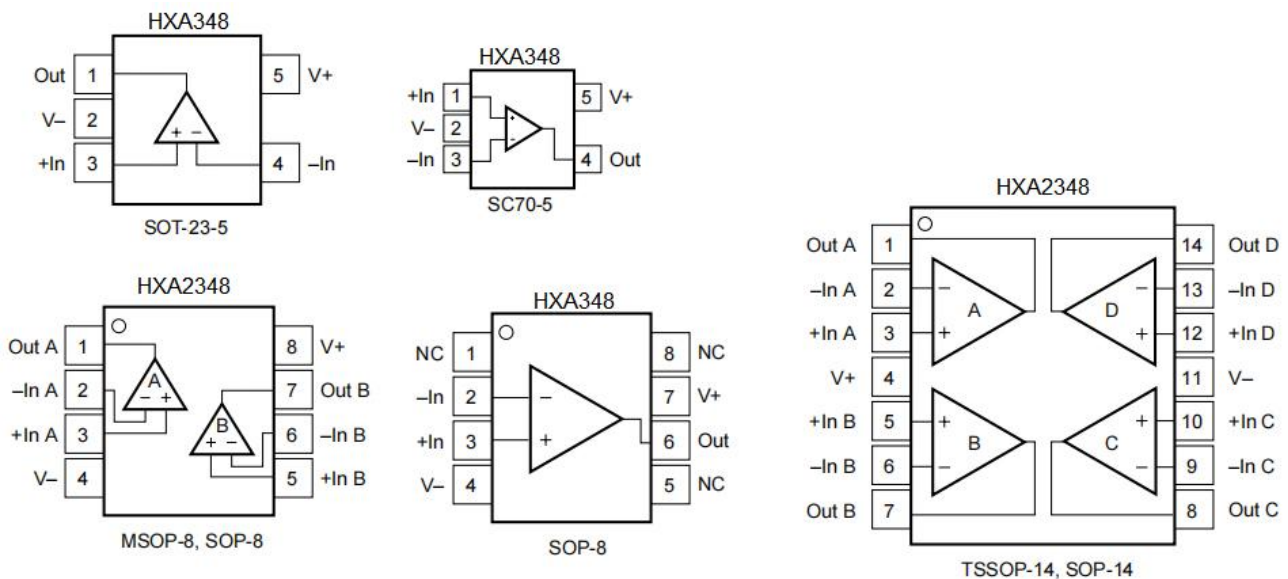
The HXA348A series amplifiers are single supply, low-power, CMOS opamps in micro packaging. Featuring an extended bandwidth of 1MHz, and a supply current of 45μA, the HXA348A series is useful for low-power applications on single supplies of 2.1V to 5.5V. Low supply current of 45μA, and an input bias current of 0.5pA, make the HXA348A series an optimal candidate for low-power, high-impedance applications such as smoke detectors and other sensors.

The HXA348A is available in the miniature SC70-5, SOT23-5 and SOP-8 packages. The HXA2348A is available in MSOP-8 and SOP-8 packages, and the HXA4348A is offered in space-saving TSSOP-14 and SOP-14 packages. The extended temperature range of -40°C to +125°C over all supply voltages offers additional design flexibility.

APPLICATIONS

- Portable Equipment
- Battery-Powered Equipment
- Smoke Alarms
- CO Detectors
- Medical Instrumentation

PIN ASSIGNMENT



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

CONDITION	MIN	MAX	UNITS
Supply Voltage		7.5	V
Signal Input Terminals Voltage ⁽²⁾	(V-)-0.5	(V+)+0.5	V
Signal Input Terminals Current ⁽²⁾	10		mA
Output Short-Circuit ⁽³⁾	Continuous		
Operating Temperature	-40	+125	°C
Storage Temperature	-65	+150	°C
Junction Temperature	150		°C
Lead Temperature (soldering, 10s)	245		°C

NOTES:

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only. Functional operation of the device at these conditions, or beyond the specified operating conditions, is not implied. (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less. (3) Short-circuit to ground, one amplifier per package.

**ELECTROSTATIC DISCHARGE SENSITIVITY**

This integrated circuit can be damaged by ESD. HGSEMI recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

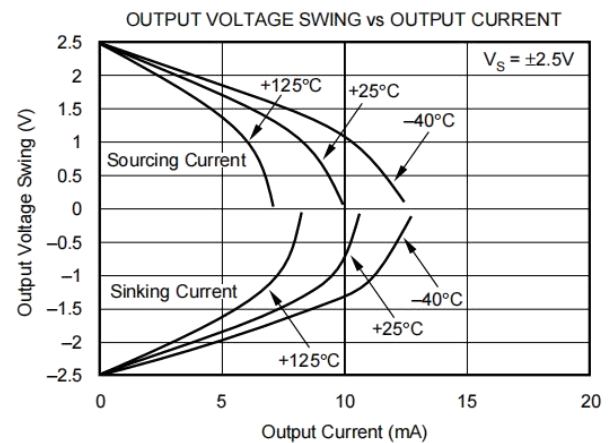
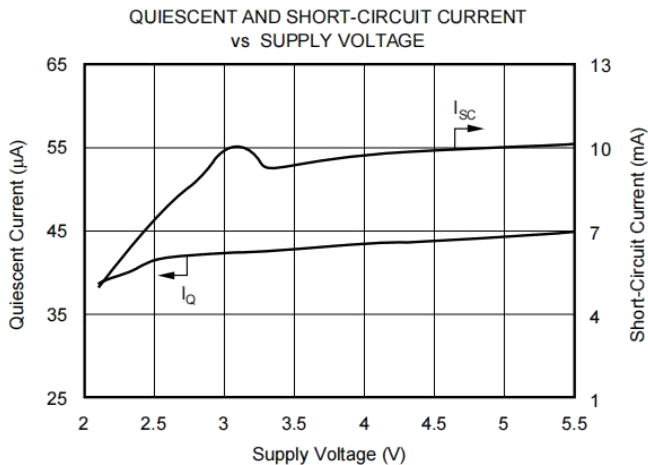
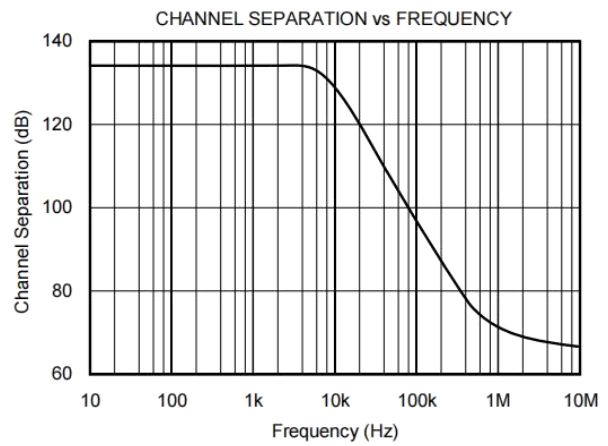
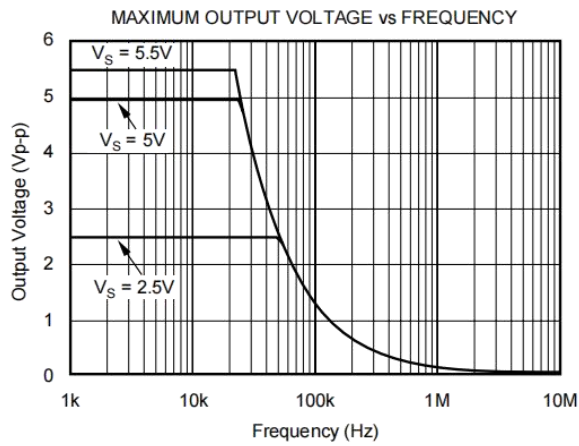
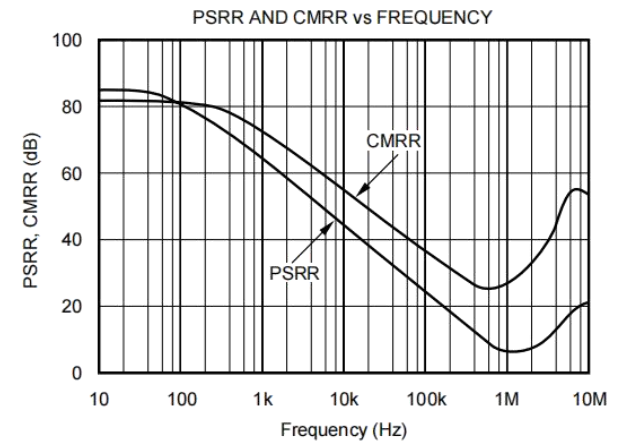
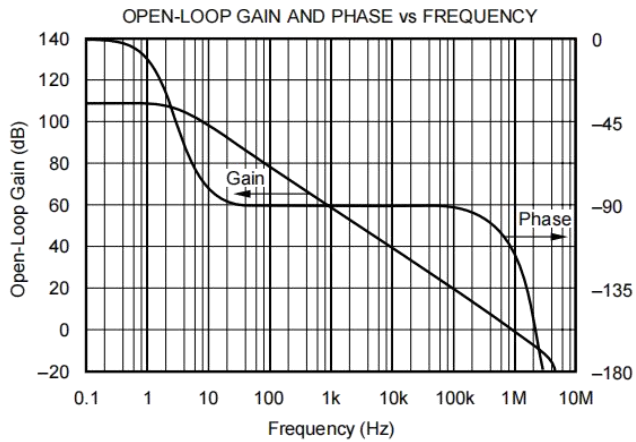
ELECTRICAL CHARACTERISTICS: $V_S = 2.5V$ to $5.5V$

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$ At $T_A = +25^{\circ}C$, $R_L = 100k\Omega$ connected to $V_S/2$ and $V_{OUT} = V_S/2$, unless otherwise noted.

PARAMETER	CONDITION	HXA348A/HXA2348A/HXA4348A			UNITS
		MIN	TYP	MAX	
OFFSET VOLTAGE	VS = 5V, VCM = (V-) + 0.8V VS = 2.5V to 5.5V, VCM < (V+) – 1.7V VS = 2.5V to 5.5V, VCM < (V+) – 1.7V		1	5	mV
Input Offset Voltage VOS				6	mV
Over Temperature			4		μ/C
DriftdVOS/dT		60		175	μ/V
vs Power SupplyPSRR		0.2		300	μ/V
Over Temperature					μ/V
Channel Separation, dcf = 1kHz			134		dB
INPUT VOLTAGE RANGE					
Common-Mode Voltage Range VCM		(V-) – 0.2		(V+) + 0.2	V
Common-Mode Rejection Ratio CMRR	(V-)-0.2V<VCM<(V+)-1.7V	70	82		dB
over Temperature	(V-)-0.2V<VCM<(V+)-1.7V	66			dB
	VS=5.5V,(V-)-0.2<VCM<(V+)+0.2V	60	71		dB
over Temperature	VS=5.5V,(V-)<VCM<(V+)	56			dB
INPUT BIAS CURRENT					
Input Bias Current IB			0.5	10	pApA
Input Offset Current IOS			0.5	10	
INPUT IMPEDANCE			1013 3		Ω pF
Differential Common-Mode			1013 6		Ω pF
NOISE					
Input Voltage Noise, f = 0.1Hz to 10Hz	VCM < (V+) – 1.7V		10		Vp-p
Input Voltage Noise Density, f = 1kHz eN			35		nV/Hz
Input Current Noise Density, f = 1kHz iN			4		fA/Hz
OPEN-LOOP GAIN					
Open-Loop Voltage Gain AOL	VS=5V,RL=100KΩ,0.025V<VO<4.975V	94	108		dB
over Temperature	VS=5V,RL=100KΩ,0.025V<VO<4.975V	90			dB
	VS=5V,RL=5KΩ,0.125V<VO<4.875V	90	98		dB
over Temperature	VS=5V,RL=5KΩ,0.125V<VO<4.875V	88			dB
OUTPUT					
Voltage Output Swing from Rail	RL = 100kΩ, AOL > 94dB		18	25	mV
over Temperature	RL = 100kΩ, AOL > 90dB			25	mV
	RL = 5kΩ, AOL > 90dB		100	125	mV
over Temperature	RL = 5kΩ, AOL > 88dB			125	mV
Short-Circuit Current ISC			10		mA
Capacitive Load Drive CL OAD		See Ty	pical Characte	ristics	
FREQUENCY RESPONSE					
Gain-Bandwidth Product GBW	CL = 100pF		1		MHz
Slew Rate SR	G = +1		0.5		V/s
Settling Time, 0.1% ts	VS = 5.5V, 2V Step, G = +1		5		μs
0.01%	VS = 5.5V, 2V Step, G = +1		7		μs
Overload Recovery Time	VIN • Gain > VS		1.6		μs
Total Harmonic Distortion + Noise THD+N	VS = 5.5V, VO = 3Vp-p, G = +1, f = 1kHz		0.0023		%
POWER SUPPLY					
Specified Voltage Range VS		2.5		5.5	V
Minimum Operating Voltage			2.1 to 5.5		V
Quiescent Current (per amplifier) IQ	Io = 0		45	65	μA
over Temperature				75	μA
TEMPERATURE RANGE					
Specified Range		–40		125	°C
Operating Range		–65		150	°C
Storage Range		–65		150	°C
Thermal Resistance JA					
SOT23-5 Surface-Mount			200		°C/W
SOT23-8 Surface-Mount			150		°C/W
MSOP-8 Surface-Mount			150		°C/W
SO-8 Surface-Mount			150		°C/W
SO-14 Surface-Mount			100		°C/W
TSSOP-14 Surface-Mount			100		°C/W
SC70-5 Surface-Mount			250		°C/W

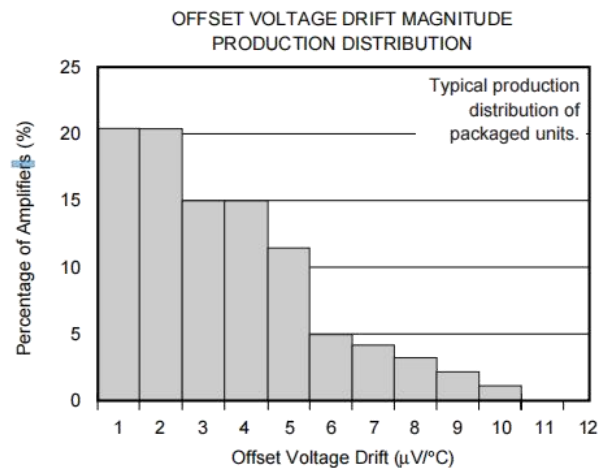
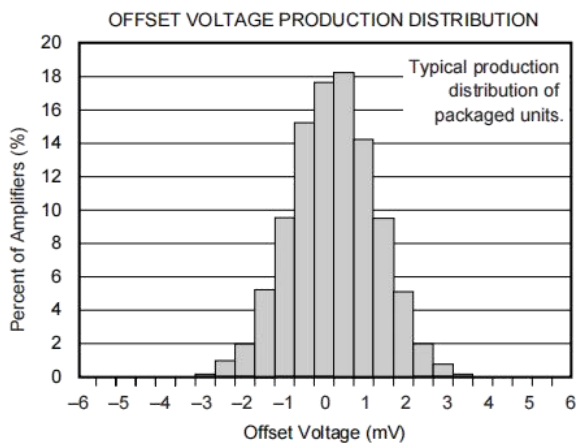
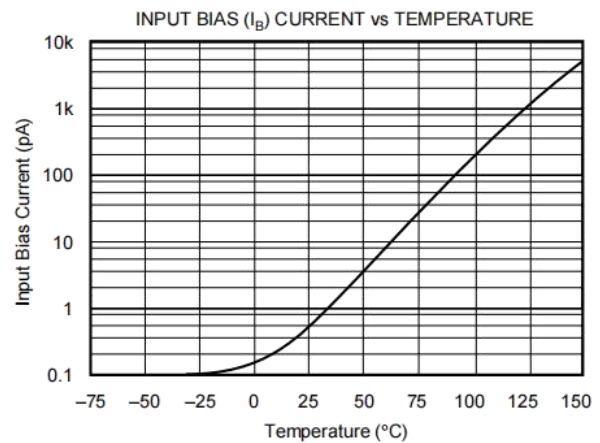
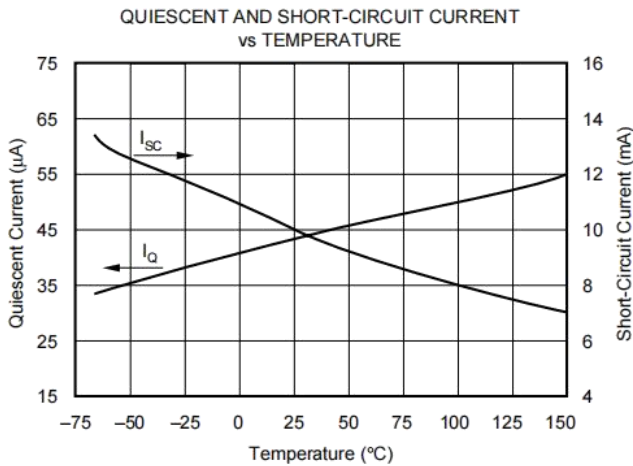
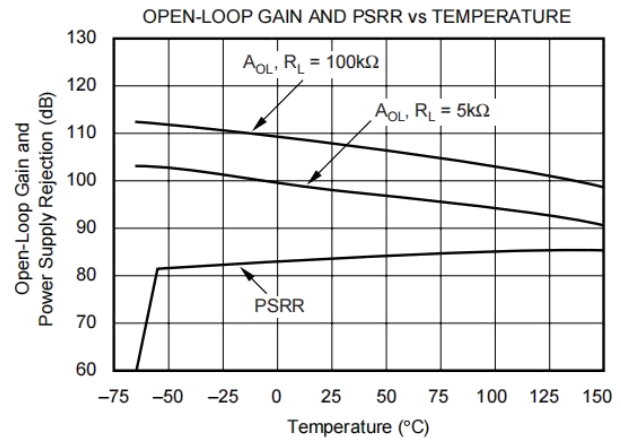
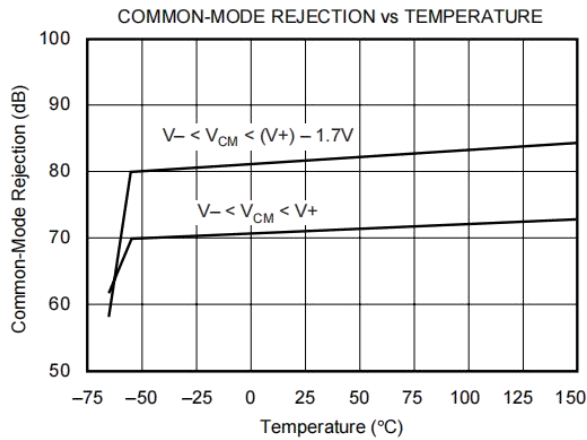
TYPICAL CHARACTERISTICS

At $T_A = +25^\circ\text{C}$, $R_L = 100\text{k}\Omega$ connected to $V_S / 2$ and $V_{OUT} = V_S / 2$, unless otherwise noted.



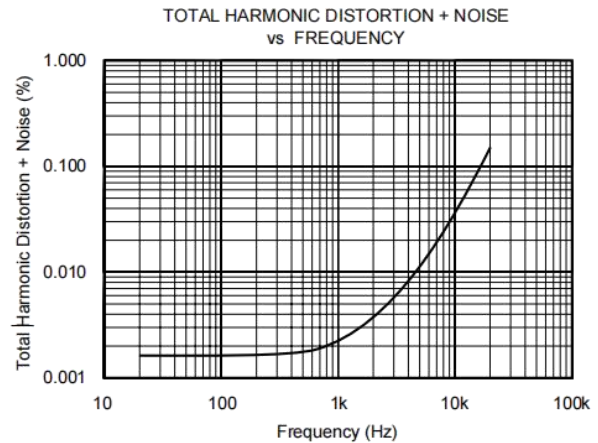
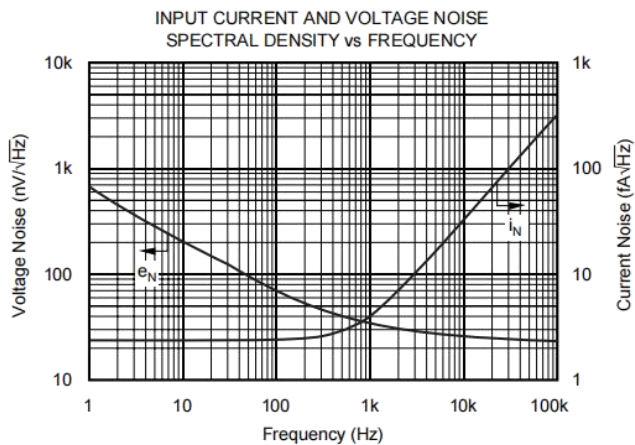
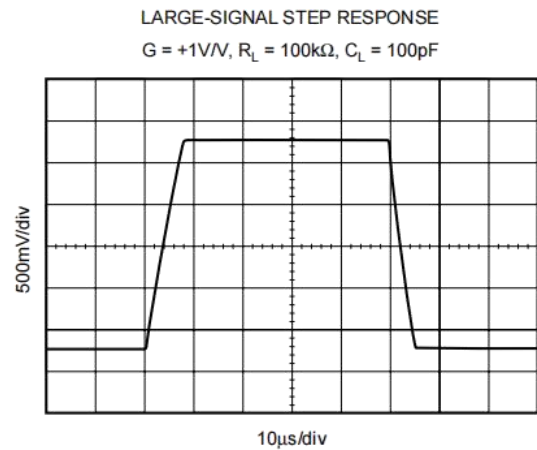
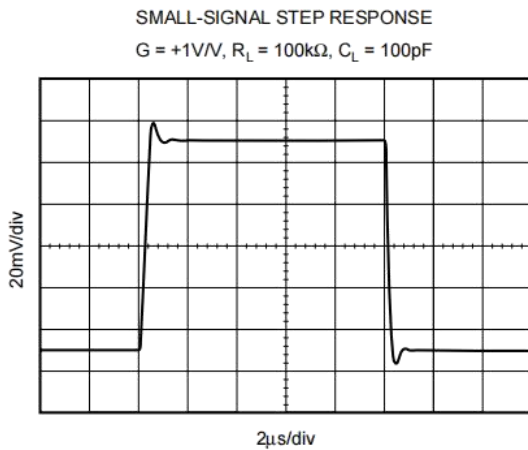
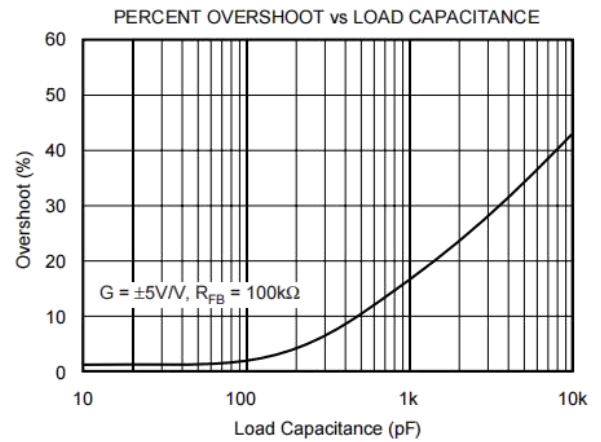
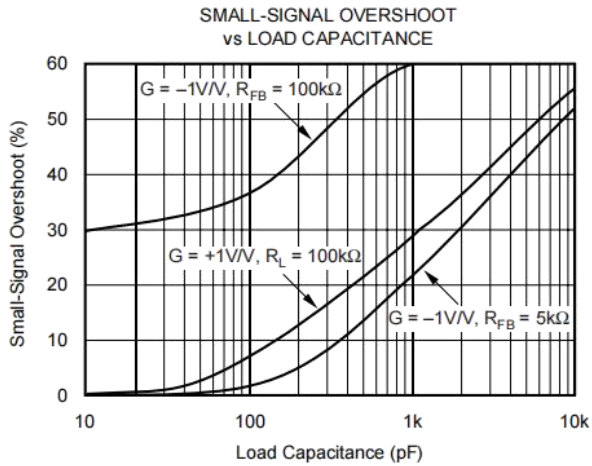
TYPICAL CHARACTERISTICS (Cont.)

At $T_A = +25^\circ\text{C}$, $R_L = 100\text{k}\Omega$ connected to $V_S / 2$ and $V_{OUT} = V_S / 2$, unless otherwise noted.



TYPICAL CHARACTERISTICS (Cont.)

At $T_A = +25^\circ\text{C}$, $R_L = 100\text{k}\Omega$ connected to $V_S / 2$ and $V_{OUT} = V_S / 2$, unless otherwise noted



APPLICATIONS INFORMATION

HXA348A series op amps are unity-gain stable and suitable for a wide range of general-purpose applications.

The HXA348A series features wide bandwidth and unity-gain stability with rail-to-rail input and output for increased dynamic range. Figure 1 shows the input and output waveforms for the HXA348A in unity-gain configuration. Operation is from a single +5V supply with a 100kΩ load connected to VS/2. The input is a 5Vp-p sinusoid. Output voltage is approximately 4.98Vp-p. Power-supply pins should be bypassed with 0.01μF ceramic capacitors.

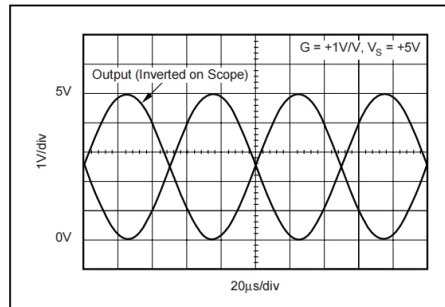


FIGURE 1. The HXA348A Features Rail-to-Rail Input/Output.

OPERATING VOLTAGE

HXA348A series op amps are fully specified and tested from +2.5V to +5.5V. However, supply voltage may range from +2.1V to +5.5V. Parameters are tested over the specified supply range—a unique feature of the HXA348A series. In addition, all temperature specifications apply from -40°C to +125°C. Most behavior remains virtually unchanged throughout the full operating voltage range. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics.

COMMON-MODE VOLTAGE RANGE

The input common-mode voltage range of the HXA348A series extends 200mV beyond the supply rails. This is achieved with a complementary input stage—an N-channel input differential pair in parallel with a P-channel differential pair. The N-channel pair is active for input voltages close to the positive rail, typically $(V+) - 1.2V$ to 300mV above the positive supply, while the P-channel pair is on for inputs from 300mV below the negative supply to approximately $(V+) - 1.4V$. There is a small transition region, typically $(V+) - 1.4V$ to $(V+) - 1.2V$, in which both pairs are on. This 200mV transition region, shown in Figure 2, can vary $\pm 300mV$ with process variation. Thus, the transition region (both stages on) can range from $(V+) - 1.7V$ to $(V+) - 1.5V$ on the low end, up to $(V+) - 1.1V$ to $(V+) - 0.9V$ on the high end. Within the 200mV transition region PSRR, CMRR, offset voltage, offset drift, and THD may be degraded compared to operation outside this region.

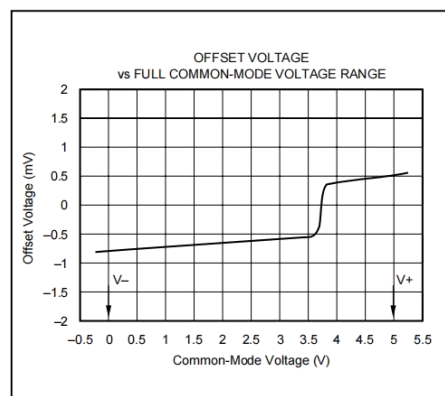


FIGURE 2. Behavior of Typical Transition Region at Room Temperature.

RAIL-TO-RAIL INPUT

The input common-mode range extends from $(V-) - 0.2V$ to $(V+) + 0.2V$. For normal operation, inputs should be limited to this range. The absolute maximum input voltage is 500mV beyond the supplies. Inputs greater than the input common-mode range but less than the maximum input voltage, while not valid, will not cause any damage to the op amp. Unlike some other op amps, if input current is limited the inputs may go beyond the power supplies without phase inversion, as shown in Figure 3.

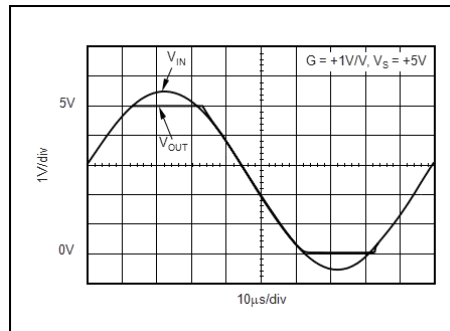


FIGURE 3. HXA348A—No Phase Inversion with Inputs Greater than the Power-Supply Voltage.

Normally, input currents are 0.5pA. However, large inputs (greater than 500mV beyond the supply rails) can cause excessive current to flow in or out of the input pins. Therefore, as well as keeping the input voltage below the maximum rating, it is also important to limit the input current to less than 10mA. This is easily accomplished with an input voltage resistor, as shown in Figure 4.

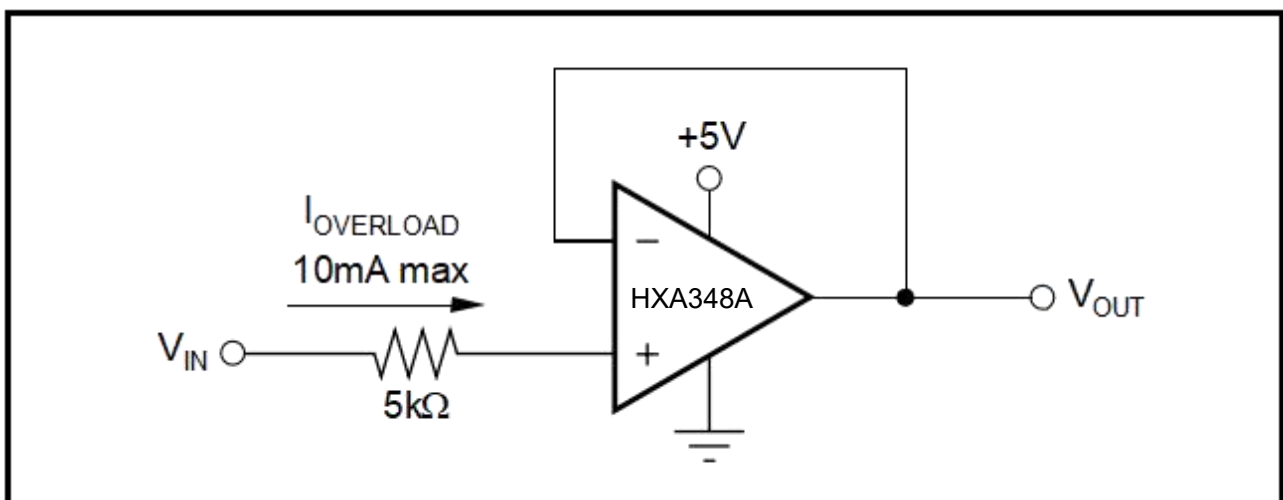


FIGURE 4. Input Current Protection for Voltages Exceeding the Supply Voltage.

RAIL-TO-RAIL OUTPUT

A class AB output stage with common-source transistors is used to achieve rail-to-rail output. This output stage is capable of driving 5kΩ loads connected to any potential between $V+$ and ground. For light resistive loads ($> 100k\Omega$), the output voltage can typically swing to within 18mV from supply rail. With moderate resistive loads (10kΩ to 50kΩ), the output voltage can typically swing to within 100mV of the supply rails while maintaining high open-loop gain (see the typical characteristic “Output Voltage Swing vs Output Current”).

CAPACITIVE LOAD AND STABILITY

The HXA348A in a unity-gain configuration can directly drive up to 250pF pure capacitive load. Increasing the gain enhances the amplifier's ability to drive greater capacitive loads (see the typical characteristic "Small-Signal Overshoot vs Capacitive Load"). In unity-gain configurations, capacitive load drive can be improved by inserting a small (10Ω to 20Ω) resistor, R_S , in series with the output, as shown in Figure 5. This significantly reduces ringing while maintaining DC performance for purely capacitive loads. However, if there is a resistive load in parallel with the capacitive load, a voltage divider is created, introducing a Direct Current (DC) error at the output and slightly reducing the output swing. The error introduced is proportional to the ratio R_S/R_L , and is generally negligible.

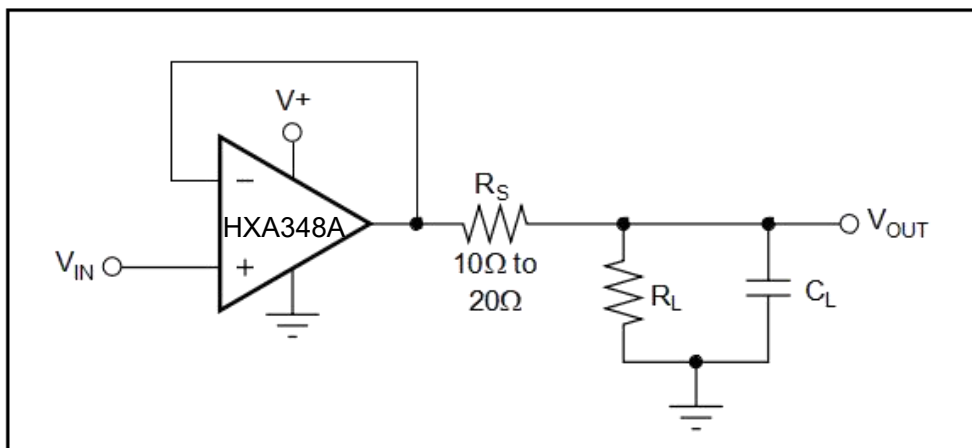


FIGURE 5. Series Resistor in Unity-Gain Buffer Configuration Improves Capacitive Load Drive.

In unity-gain inverter configuration, phase margin can be reduced by the reaction between the capacitance at the op amp input, and the gain setting resistors, thus degrading capacitive load drive. Best performance is achieved by using small valued resistors. For example, when driving a 500pF load, reducing the resistor values from $100k\Omega$ to $5k\Omega$ decreases overshoot from 55% to 13% (see the typical characteristic "Small-Signal Overshoot vs. Load Capacitance"). However, when large valued resistors cannot be avoided, a small (4pF to 6pF) capacitor, C_{FB} , can be inserted in the feedback, as shown in Figure 6. This significantly reduces overshoot by compensating the effect of capacitance, C_{IN} , which includes the amplifier's input capacitance and PC board parasitic capacitance.

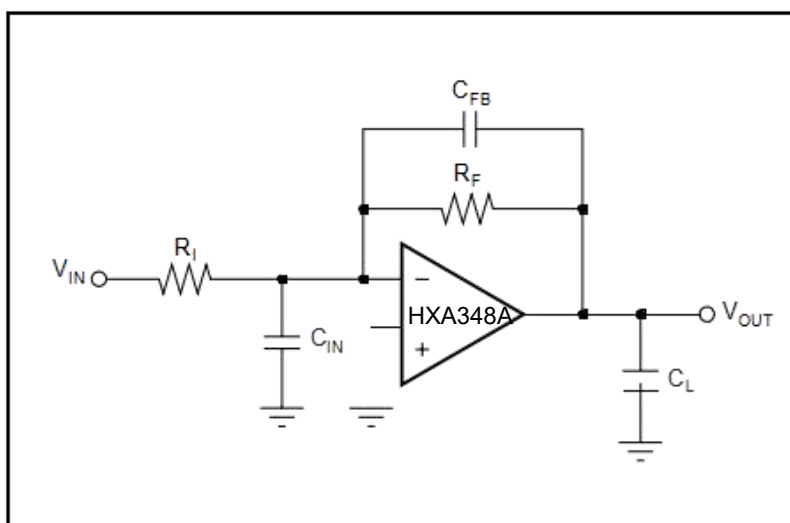


FIGURE 6. Improving Capacitive Load Drive.

DRIVING A/D CONVERTERS

The HXA348A series op amps are optimized for driving medium-speed sampling Analog-to-Digital Converters (ADCs). The HXA348A op amps buffer the ADCs input capacitance and resulting charge injection while providing signal gain.

The HXA348A in a basic noninverting configuration driving the ADS7822, see Figure 7. The ADS7822 is a 12-bit, microPOWER sampling converter in the MSOP-8 package. When used with the low-power, miniature packages of the HXA348A, the combination is ideal for space-limited, low-power applications. In this configuration, an RC network at the ADC's input can be used to provide for anti-aliasing filter and charge injection current.

The HXA348A in noninverting configuration driving ADS7822 limited, low-power applications. In this configuration, an RC network at the ADC's input can be used to provide for anti-aliasing filter and charge injection current. See Figure 8 for the HXA2348A driving an ADS7822 in a speech bandpass filtered data acquisition system. This small, low-cost solution provides the necessary amplification and signal conditioning to interface directly with an electret microphone. This circuit will operate with $V_S = 2.7V$ to $5V$ with less than $250\mu A$ typical quiescent current.

FIGURE 7. HXA348Ain Noninverting Configuration Driving ADS7822.

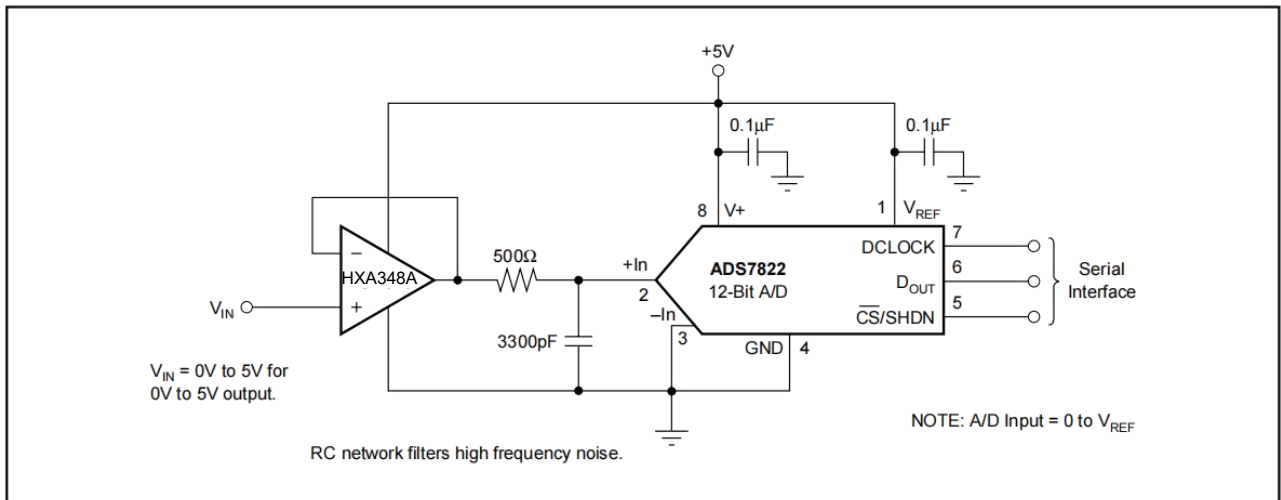
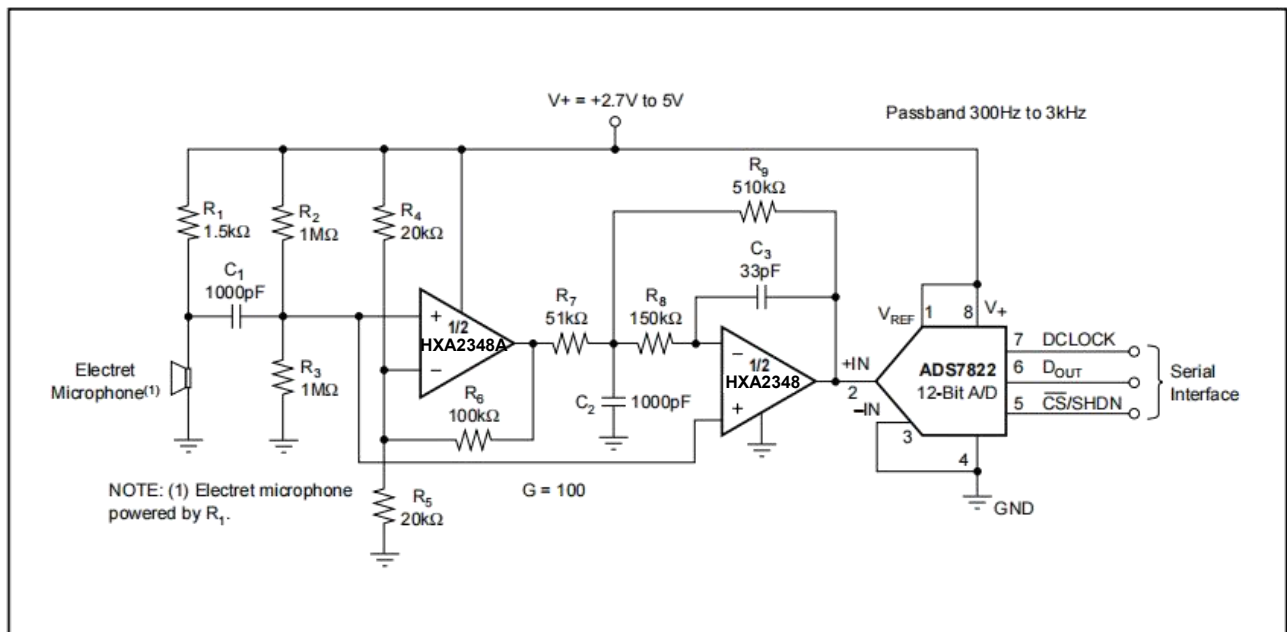
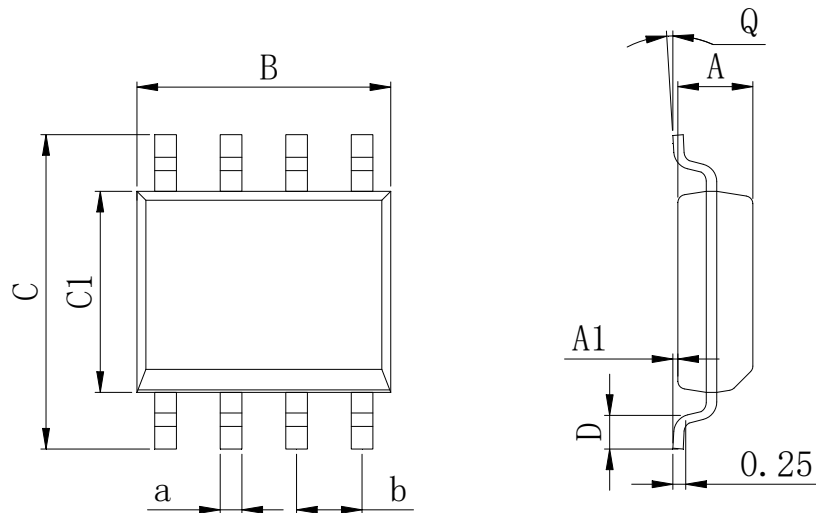


FIGURE 8. HXA2348A as a Speech Bandpass Filtered Data Acquisition System.



PHYSICAL DIMENSIONS

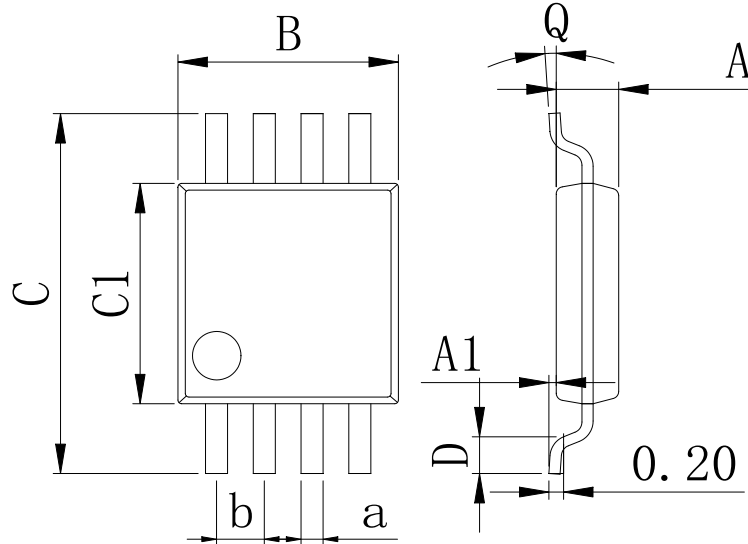
SOP-8



Dimensions In Millimeters(SOP-8)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

MSOP-8

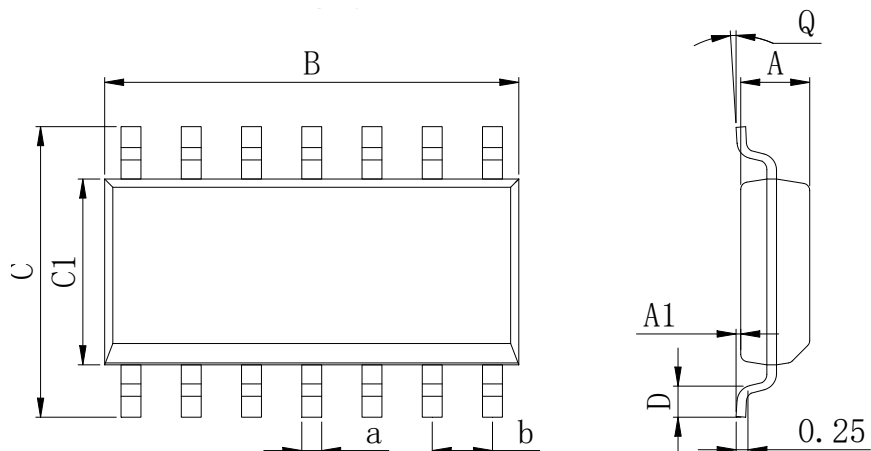


Dimensions In Millimeters(MSOP-8)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	

PHYSICAL DIMENSIONS

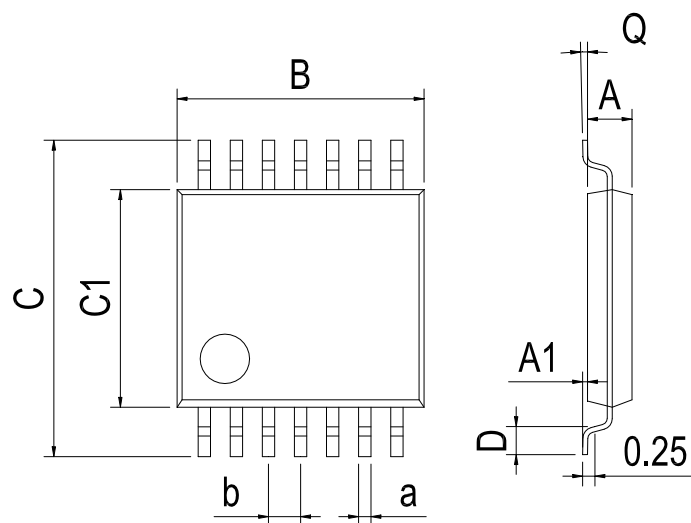
SOP-14



Dimensions In Millimeters(SOP-14)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	

TSSOP-14

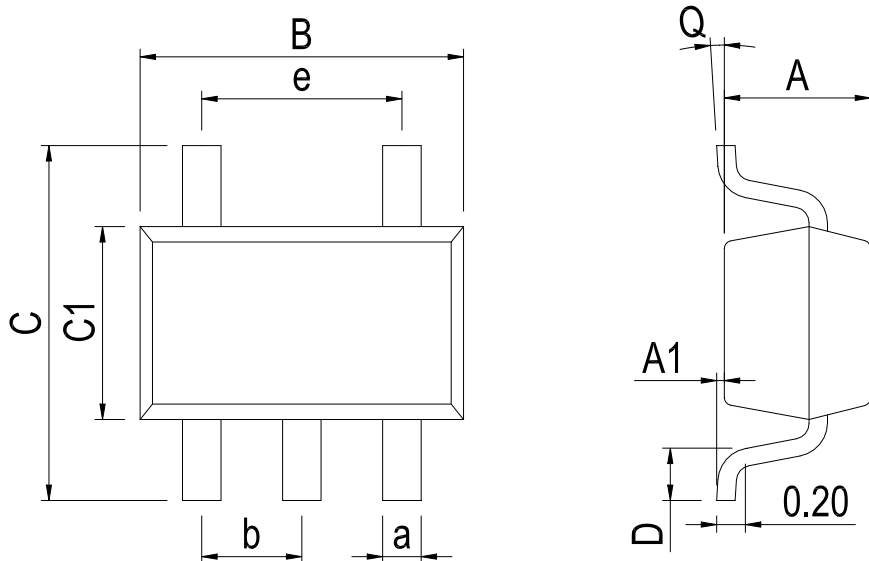


Dimensions In Millimeters(TSSOP-14)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	

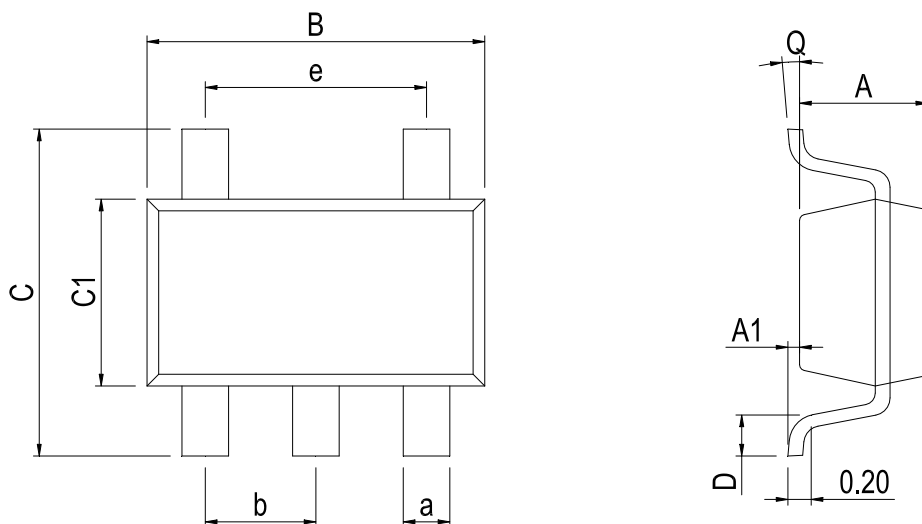
PHYSICAL DIMENSIONS

SOT-23-5


Dimensions In Millimeters(SOT-23-5)

Symbol:	A	A1	B	C	C1	D	Q	a	b	e
Min:	1.00	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.95 BSC	1.90 BSC
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.50		

SC70-5


Dimensions In Millimeters(SC70-5)

Symbol:	A	A1	B	C	C1	D	Q	a	b	e
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.15	0.65 BSC	1.30 BSC
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.35		

REVISION HISTORY

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2019-12	New	1-17
V1.1	2023-7	Update Lead Temperature、 Update encapsulation type	3、 1
V1.2	2024-11	Update SOT-23-5 Physical dimension	15

IMPORTANT STATEMENT:

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